



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of:

Brask et al.

Examiner: Christian D. Wilson

Application No.: 10/828,958

Art Unit: 2891

Filed: April 20, 2004

For: A METHOD FOR MAKING A
SEMICONDUCTOR DEVICE HAVING A
HIGH-K GATE DIELECTRIC LAYER
AND A METAL GATE ELECTRODE

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT

Dear Examiner:

This is in response to the Office Action mailed November 18, 2005. Applicants respectfully request the Examiner to enter this Preliminary Amendment and consider the following remarks.

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage in an envelope addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

on January 18, 2006
Date of Deposit

Teresa Mattox
Name of Person Mailing Correspondence

Teresa Mattox
Signature

1/18/06
Date